

# STPS40L45C

# Low drop power Schottky rectifier

# **A1** Κ A2 D<sup>2</sup>PAK STPS40L45CG A2 ∛ĸ A2 ă1<sup>K</sup> <sup>∃</sup>A1 **TO-220AB** TO-247 STPS40L45CT STPS40L45CW

## **Features**

- Low forward voltage drop meaning very small . conduction losses
- Low switching losses allowing high frequency • operation
- Avalanche capability specified •

This is information on a product in full production.

#### **Datasheet - production data**

### Description

Dual center tap Schottky barrier rectifier designed for high frequency switched mode power supplies and DC to DC converters.

Packaged in TO-220AB, TO-247 and D<sup>2</sup>PAK these devices are intended for use in low voltage,

high frequency inverters, free-wheeling and polarity protection applications.

#### Table 1. Device summary

	-
I <sub>F(AV)</sub>	2 x 20 A
V <sub>RRM</sub>	45 V
T <sub>j</sub> (max)	150° C
V <sub>F</sub> (max)	0.49 V

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# 1 Characteristics

Symbol	Paramet	Value	Unit		
V <sub>RRM</sub>	Repetitive peak reverse voltage			45	V
I <sub>F(RMS)</sub>	Forward rms current			30	А
I <sub>F(AV)</sub>	Average forward current	$ \begin{array}{c c} T_c = 130^{\circ} \ C \\ \delta = 0.5 \end{array}  \begin{array}{c} \text{Per diode} \\ \text{Per device} \end{array} $		20 40	A
I <sub>FSM</sub>	Surge non repetitive forward current	t <sub>p</sub> = 10 ms Sin	iusoidal	220	А
I <sub>RRM</sub>	Repetitive peak reverse current	t <sub>p</sub> = 2 μs squa	re F = 1 kHz	2	А
I <sub>RSM</sub>	Non repetitive peak reverse current	everse current t <sub>p</sub> = 100 µs square			А
P <sub>ARM</sub>	Repetitive peak avalanche power $t_p = 1 \ \mu s \ T_j = 25^{\circ} C$			8100	W
T <sub>stg</sub>	Storage temperature range			-65 to + 150	°C
Тj	Maximum operating junction temperature <sup>(1)</sup>			150	°C
dV/dt	Critical rate of rise of reverse voltage			10000	V/µs
dPtot	1 1 1 1 1 1 1			•	

#### Table 2. Absolute Ratings (limiting values, per diode)

1.  $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$  condition to avoid thermal runaway for a diode on its own heatsink

#### Table 3. Thermal resistances

Symbol	Parameter	Value	Unit	
R <sub>th (j-c)</sub>	Junction to case	Per diode Total	1.5 0.8	°C/W
R <sub>th(c)</sub>	Coupling		0.1	°C/W

When the diodes 1 and 2 are used simultaneously:

 $\Delta T_{j}(\text{diode 1}) = P(\text{diode1}) \times R_{th(j-c)}(\text{Per diode}) + P(\text{diode2}) \times R_{th(c)}.$ 

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
I <sub>R</sub> <sup>(1)</sup>	$T_j = 25^\circ C$				0.6	mA	
'R`	I <sub>R</sub> <sup>(1)</sup> Reverse leakage current	T <sub>j</sub> = 125° C	$V_{R} = V_{RRM}$		140	280	mA
	) Forward valtage drag	T <sub>j</sub> = 25° C	I <sub>F</sub> = 20 A			0.53	
$V_{r}^{(1)}$		T <sub>j</sub> = 125° C	I <sub>F</sub> = 20 A		0.42	0.49	V
V <sub>F</sub> <sup>(1,)</sup> Forward voltage drop	T <sub>j</sub> = 25° C	I <sub>F</sub> = 40 A			0.69	v	
		T <sub>j</sub> = 125° C	I <sub>F</sub> = 40 A		0.6	0.7	

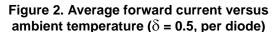
1. Pulse test:  $t_p = 380 \ \mu s, \ \delta < 2\%$ 

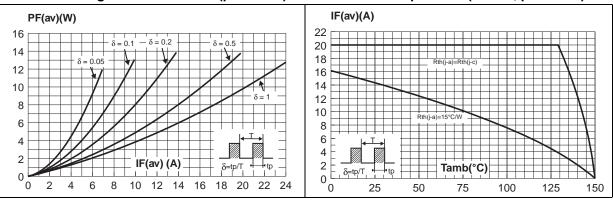
To evaluate the conduction losses use the following equation:

 $P = 0.28 \text{ x } I_{F(AV)} + 0.0105 I_{F}{}^{2}_{(RMS)}$ 



Figure 1. Average forward power dissipation versus average forward current (per diode)





versus pulse duration

Figure 3. Normalized avalanche power derating Figure 4. Normalized avalanche power derating versus junction temperature

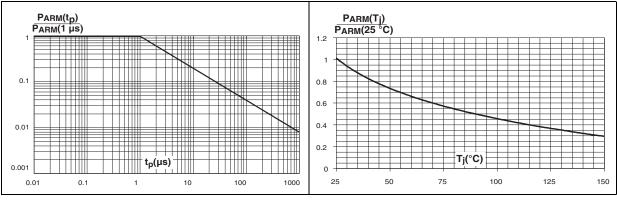
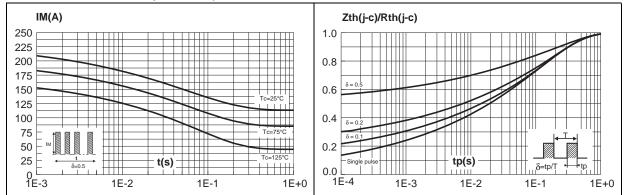


Figure 5. Non repetitive surge peak forward current versus overload duration (maximum values, per diode)

Figure 6. Relative variation of thermal impedance junction to case versus pulse duration



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Figure 7. Reverse leakage current versus reverse voltage applied (typical values, per diode)

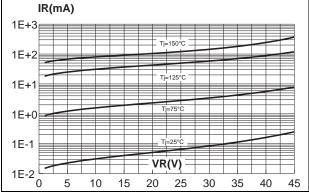
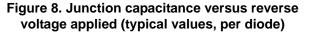


Figure 9. Forward voltage drop versus forward current (maximum values, per diode)



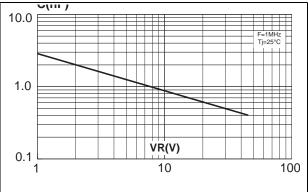
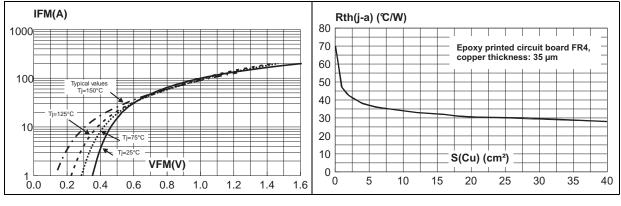


Figure 10. Thermal resistance junction to ambient versus copper surface under tab

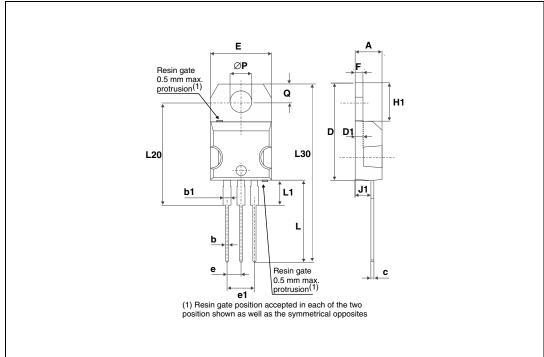




## 2 Package Information

- Epoxy meets UL94,V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.4 to 0.6 N·m (TO-220AB)
- Recommended torque value: 0.55, 1.0 N⋅m maximum (TO-247)

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK<sup>®</sup> is an ST trademark.



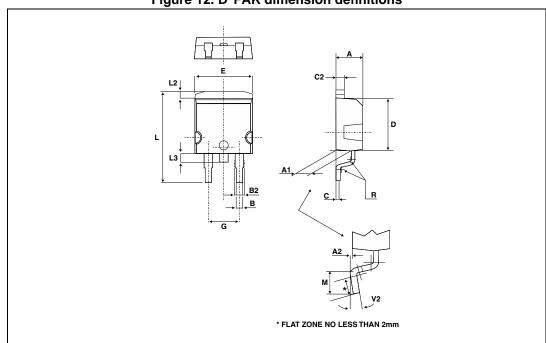




Dimensions				
Ref.	Millim	Millimeters		hes
	Min.	Max.	Min.	Max.
А	4.40	4.60	0.17	0.18
b	0.61	0.88	0.024	0.035
b1	1.14	1.70	0.045	0.067
с	0.48	0.70	0.019	0.027
D	15.25	15.75	0.60	0.62
D1	1.27	typ.	0.05	typ.
E	10	10.40	0.39	0.41
е	2.40	2.70	0.094	0.106
e1	4.95	5.15	0.19	0.20
F	1.23	1.32	0.048	0.052
H1	6.20	6.60	0.24	0.26
J1	2.40	2.72	0.094	0.107
L	13	14	0.51	0.55
L1	3.50	3.93	0.137	0.154
L20	16.40 typ.		0.64 typ.	
L30	28.90	) typ.	1.13 typ.	
ØP	3.75	3.85	0.147	0.151
Q	2.65	2.95	0.104	0.116

Table 5. TO-220AB dimension values





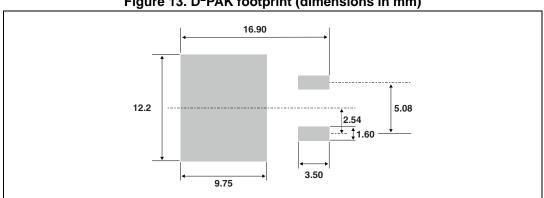
### Figure 12. D<sup>2</sup>PAK dimension definitions

### Table 6. D<sup>2</sup>PAK dimension values

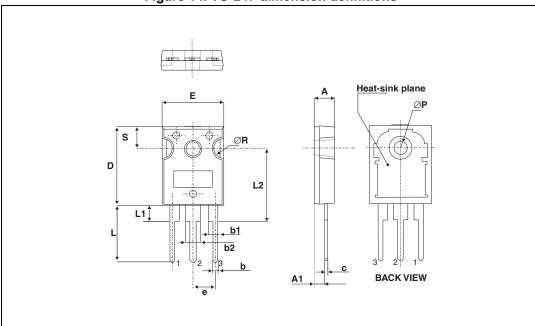
	Dimensions					
Ref.	Millin	neters	Inc	hes		
	Min.	Max.	Min.	Max.		
А	4.40	4.60	0.173	0.181		
A1	2.49	2.69	0.098	0.106		
A2	0.03	0.23	0.001	0.009		
В	0.70	0.93	0.027	0.037		
B2	1.14	1.70	0.045	0.067		
С	0.45	0.60	0.017	0.024		
C2	1.23	1.36	0.048	0.054		
D	8.95	9.35	0.352	0.368		
E	10.00	10.40	0.393	0.409		
G	4.88	5.28	0.192	0.208		
L	15.00	15.85	0.590	0.624		
L2	1.27	1.40	0.050	0.055		
L3	1.30	1.75	0.051	0.069		
М	2.29	2.79	0.090	0.110		
R	0.40	) typ.	0.016 typ.			
V2	0°	8°	0°	8°		



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### Figure 14. TO-247 dimension definitions



	Dimensions						
Ref.		Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур	Max.	
А	4.85		5.15	0.191		0.203	
A1	2.20		2.60	0.086		0.102	
b	1.00		1.40	0.039		0.055	
b1	2.00		2.40	0.078		0.094	
b2	3.00		3.40	0.118		0.133	
С	0.40		0.80	0.015		0.031	
D <sup>(1)</sup>	19.85		20.15	0.781		0.793	
Е	15.45		15.75	0.608		0.620	
е	5.30	5.45	5.60	0.209	0.215	0.220	
L	14.20		14.80	0.559		0.582	
L1	3.70		4.30	0.145		0.169	
L2	18.50 typ.			0.728 typ.			
ØP <sup>(2)</sup>	3.55		3.65	0.139		0.143	
ØR	4.50		5.50	0.177		0.217	
S	5.30	5.50	5.70	0.209	0.216	0.224	

Table 7. TO-247 dimension values

1. Dimension D plus gate protrusion does not exceed 20.5 mm

2. Resin thickness around the mounting hole is not less than 0.9 mm



# **3** Ordering Information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS40L45CG	STPS40L45CG	D <sup>2</sup> PAK	1.8g	500	Tape and reel
STPS40L45CT	STPS40L45CT	TO-220AB	2g	50	Tube
STPS40L45CW	STPS40L45CW	TO-247	4.4g	30	Tube

# 4 Revision history

Date	Revision	Description of Changes
Jul-2003	4A	Previous version
30-Oct-2013	5	Updated Package information section

#### Table 9. Document revision history



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